# 2SD1645

## Silicon NPN Epitaxial Planar Darlington Type

#### AF Amplifier

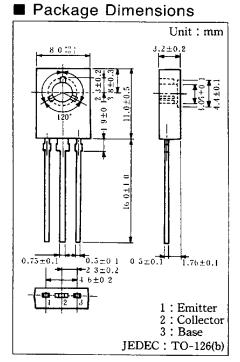
#### Features

- 60V Zener diode between built-in C and B, C and E
- Very small fluctuations in breakdown voltage
- Darlington connection
- High DC current gain (h<sub>FE</sub>)

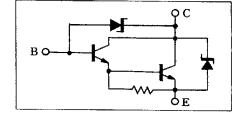
Item	Symbol	Value	Unit		
Collector-base voltage	V <sub>СВО</sub>	$60 \pm 10$	V		
Collector-emitter voltage	VCEO	$60 \pm 10$	v		
Emitter-base voltage	VEBO	5	v		
Peak collector current	I <sub>CP</sub>	1.5	A		
Collector current	Ic	1.0	А		
Collector neuror dissinction	Pc	1.2	W		
Collector power dissipation	гÇ	5.0*			
Junction temperature	T <sub>1</sub>	150	°C		
Storage temperature	Tstg	-55 - +150	Ĉ		

■ Absolute Maximum Ratings (Ta=25°C)

\*with a  $100 \times 100 \times 2$  Al heat sink at Ta=25°C



Inner Circuit



#### ■ Electrical Characteristics (Tc=25°C)

Item	Symbol	Condition	min.	typ.	max.	Unit
Collector cutoff current	I <sub>сво</sub>	$V_{CB} = 25 \text{ V}, I_E = 0$			1	μA
Emitter cutoff current	I <sub>EBO</sub>	$V_{EB} = 4 V, I_C = 0$			1	μA
Collector-base voltage	Vсво	$I_{\rm C} = 100 \ \mu {\rm A}, \ I_{\rm E} = 0$	50		70	V
Collector-emitter voltage	VCEO	$I_{\rm C} = 1  {\rm mA},  I_{\rm B} = 0$	50		70	V
Emitter-base voltage	VEBO	$I_{\rm E} = 100 \ \mu {\rm A}, \ {\rm I}_{\rm C} = 0$	5			V
DC current gain	h <sub>FE</sub> *1	$V_{CE} = 10 \text{ V}, I_C = 1.0 \text{ A}^{*2}$	4000		40000	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = 1.0 \text{ A}, I_{\rm B} = 1.0 \text{ mA}^{*2}$			1.8	V
Base-emitter saturation voltage	V <sub>BE(sat)</sub>	$I_{\rm C} = 1.0 \text{ A}, I_{\rm B} = 1.0 \text{ mA}^{*2}$			2.2	V
Transition frequency	f <sub>T</sub>	$V_{CB} = 10V, I_E = -50mA, f = 200MHz$	†	150		MHz

\*2 Pulse measurement

\*1hFE1 Classifications

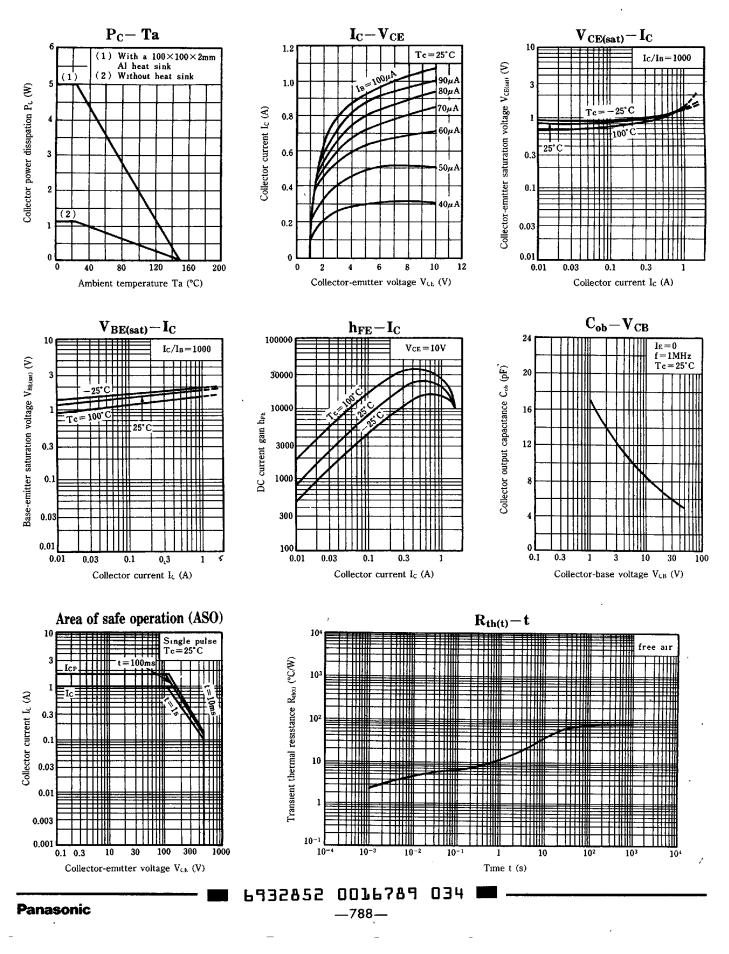
Class	Q	R	S
hFE	4000~10000	8000~20000	16000 - 40000

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